

RQA0009TXDQS

Silicon N-Channel MOS FET

REJ03G1520-0100

Rev.1.00

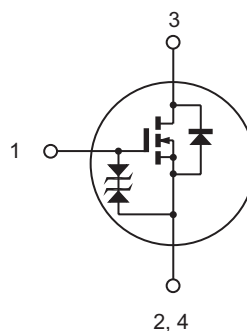
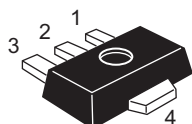
Jul 04, 2007

Features

- High Output Power, High Gain, High Efficiency
Pout = +37.8 dBm, Linear Gain = 18 dB, PAE = 65%
(V_{DS} = 6 V, f = 520 MHz)
- Compact package capable of surface mounting
- Electrostatic Discharge Immunity Test
(IEC Standard, 61000-4-2, Level4)

Outline

RENESAS Package code: PLZZ0004CA-A
(Package Name : UPAK[®])



- 1. Gate
- 2. Source
- 3. Drain
- 4. Source

Note: Marking is "TX".

*UPAK is a trademark of Renesas Technology Corp.

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	16	V
Gate to source voltage	V _{GSS}	±5	V
Drain current	I _D	3.2	A
Channel dissipation	P _{ch} ^{note}	15	W
Channel temperature	T _{ch}	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Note: Value at T_c = 25°C

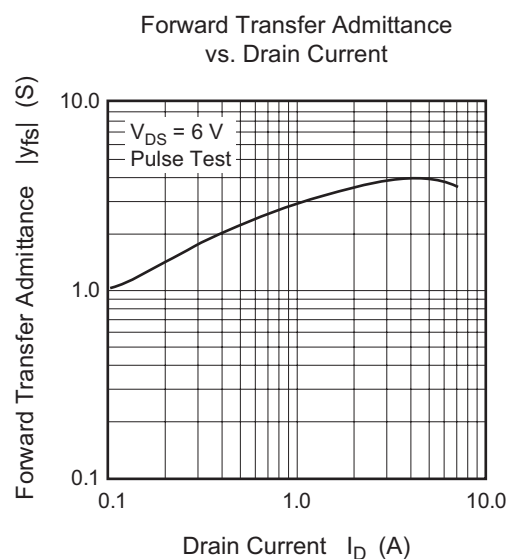
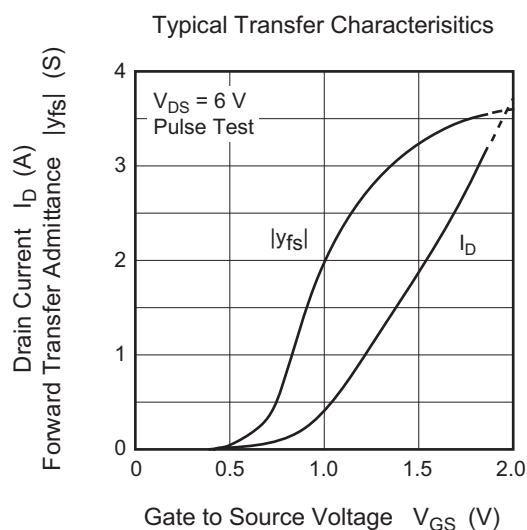
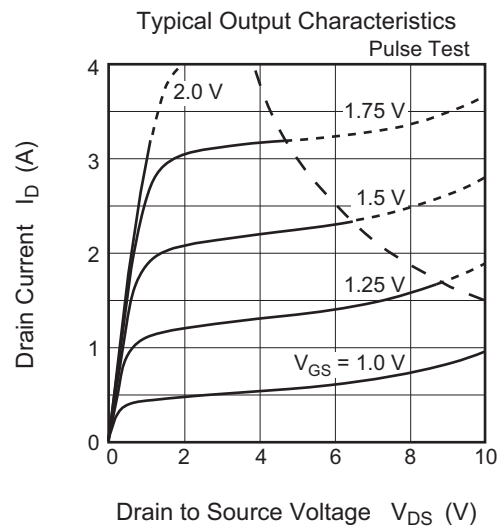
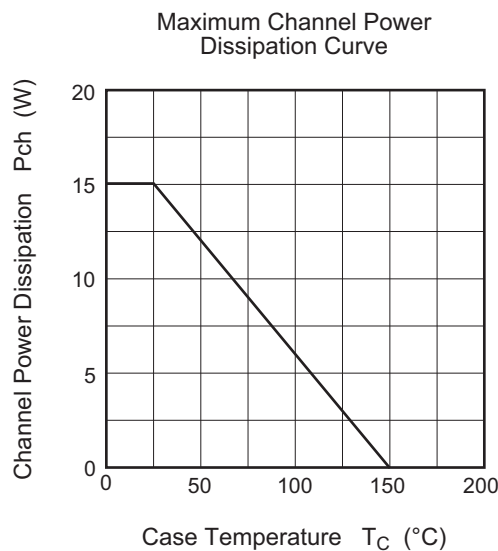
This device is sensitive to electro static discharge. An adequate careful handling procedure is requested.

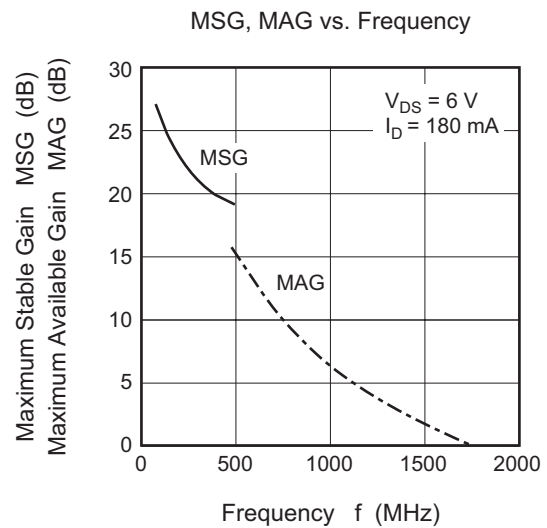
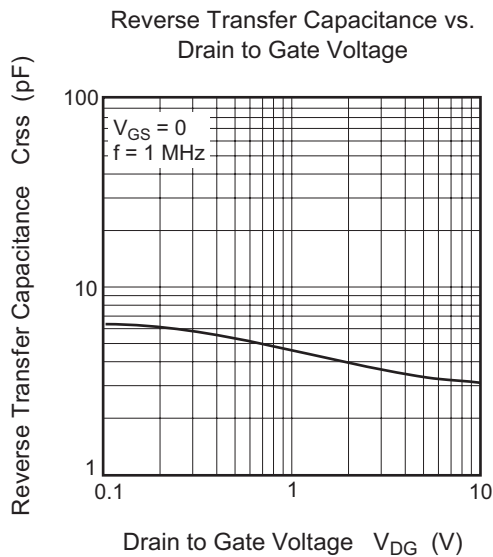
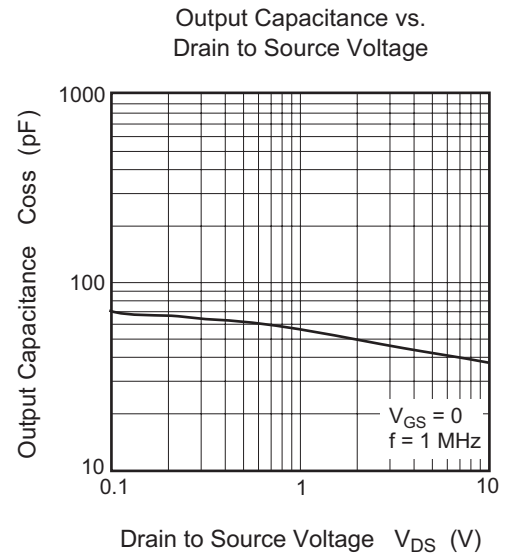
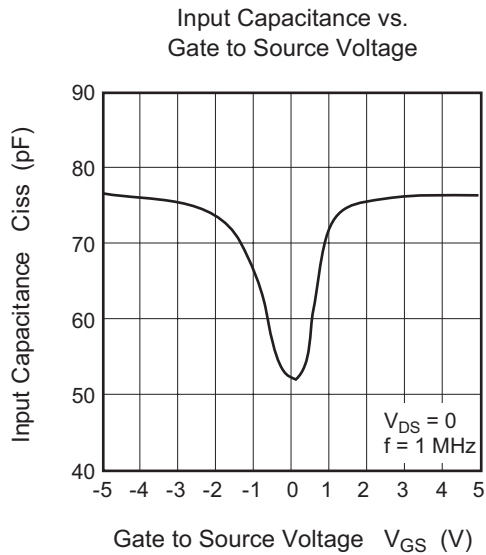
Electrical Characteristics

(Ta = 25°C)

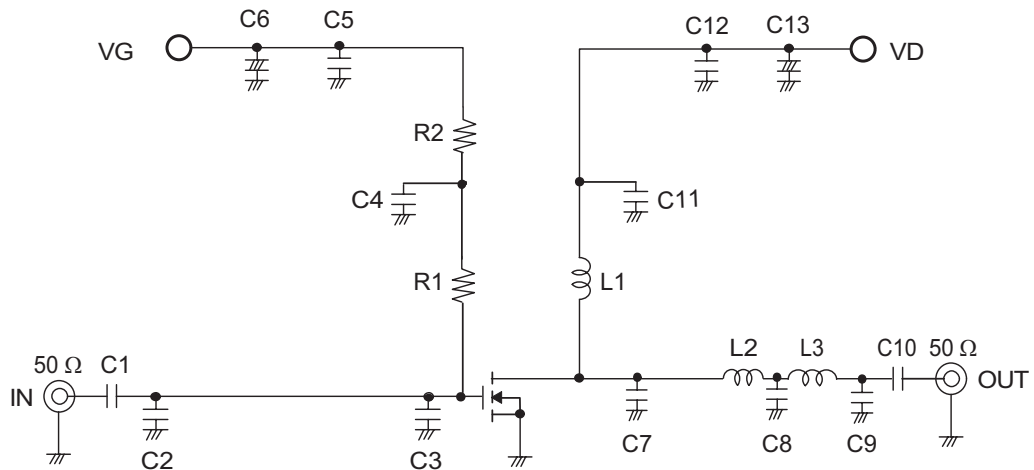
Item	Symbol	Min.	Typ	Max.	Unit	Test Conditions
Zero gate voltage drain current	I_{DSS}	—	—	15	μA	$V_{DS} = 16 V, V_{GS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 2	μA	$V_{GS} = \pm 5 V, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	0.15	0.5	0.8	V	$V_{DS} = 6 V, I_D = 1 mA$
Forward Transfer Admittance	$ y_{fs} $	2.2	3.2	4.4	S	$V_{DS} = 6 V, I_D = 1.6 A$
Input capacitance	C_{iss}	—	76	—	pF	$V_{GS} = 5 V, V_{DS} = 0, f = 1 MHz$
Output capacitance	C_{oss}	—	40	—	pF	$V_{DS} = 6 V, V_{GS} = 0, f = 1 MHz$
Reverse transfer capacitance	C_{rss}	—	3.5	—	pF	$V_{DG} = 6 V, V_{GS} = 0, f = 1 MHz$
Output Power	P_{out}	36.8	37.8	—	dBm	$V_{DS} = 6 V, I_{DQ} = 180 mA$
		4.8	6.0	—	W	$f = 520 MHz,$
Power Added Efficiency	PAE	60	65	—	%	$P_{in} = +25 dBm (316 mW)$
Output Power	P_{out}	—	35.2	—	dBm	$V_{DS} = 4.8 V, I_{DQ} = 300 mA$
		—	3.3	—	W	$f = 465 MHz,$
Power Added Efficiency	PAE	—	60	—	%	$P_{in} = +17 dBm (50 mW)$

Main Characteristics

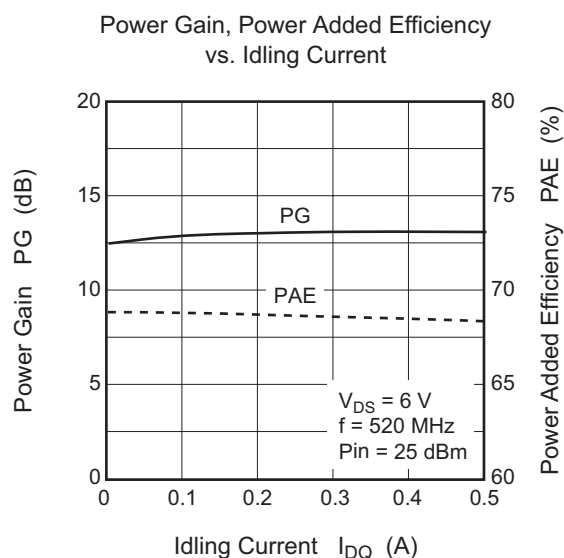
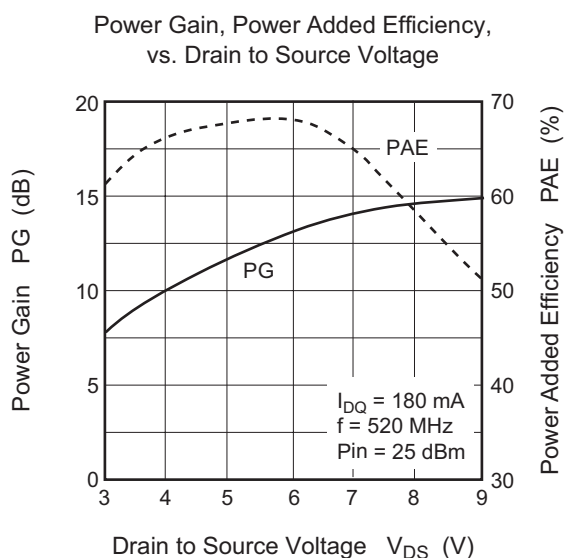
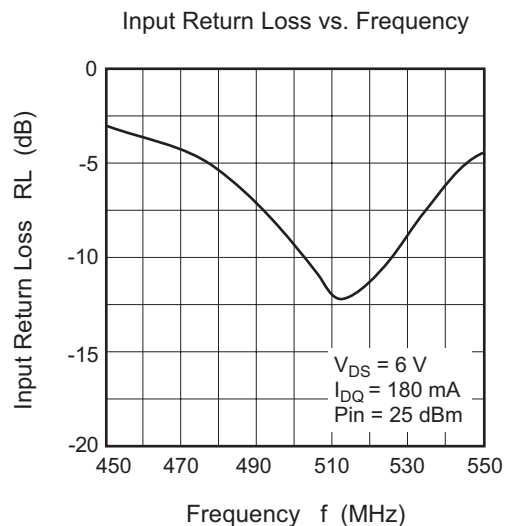
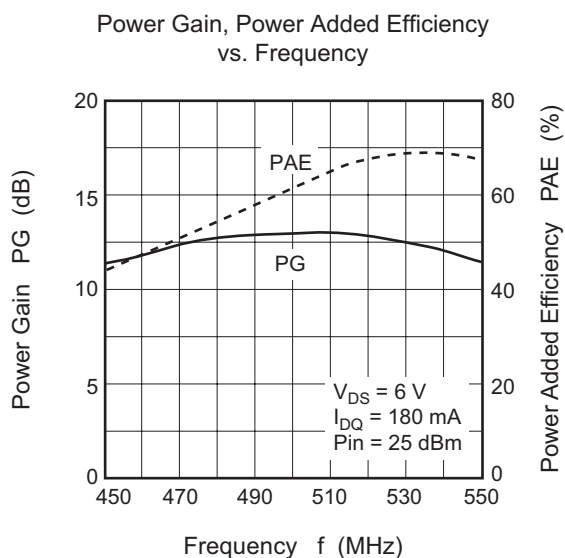
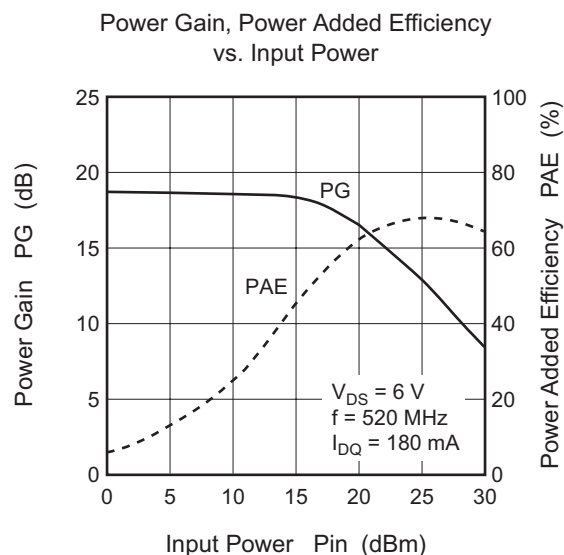
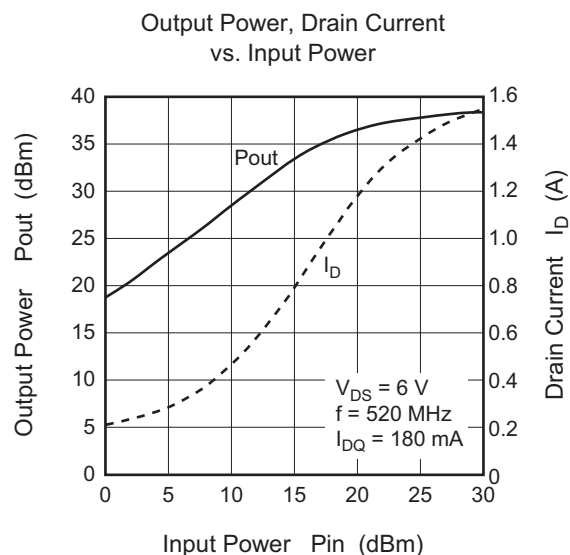




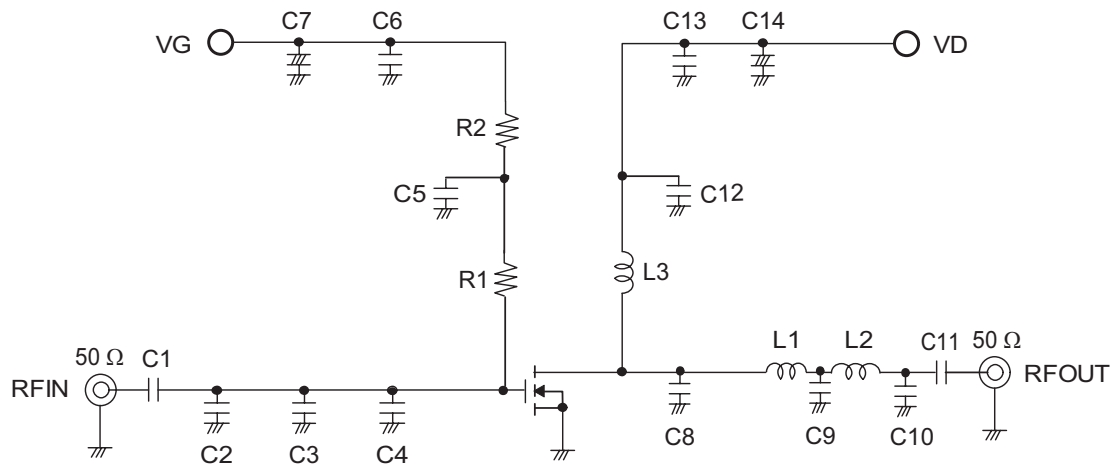
Evaluation Circuit (f = 520 MHz)



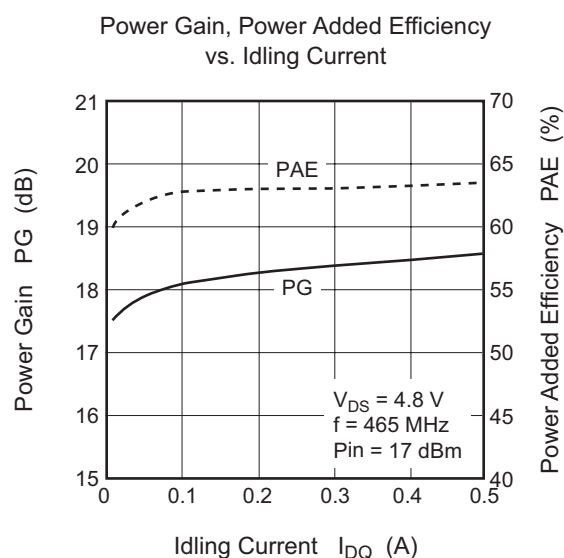
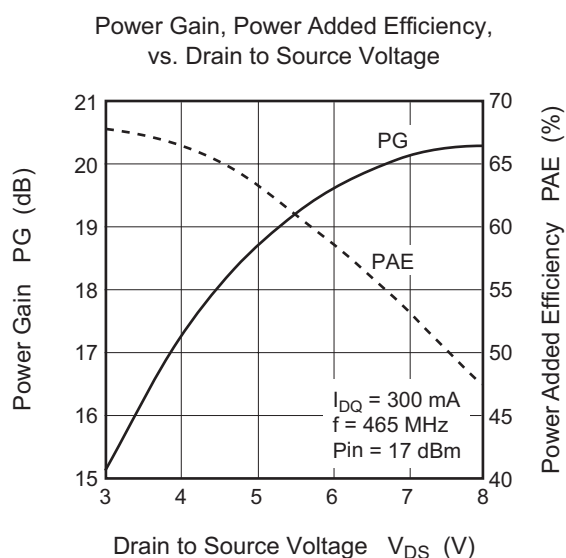
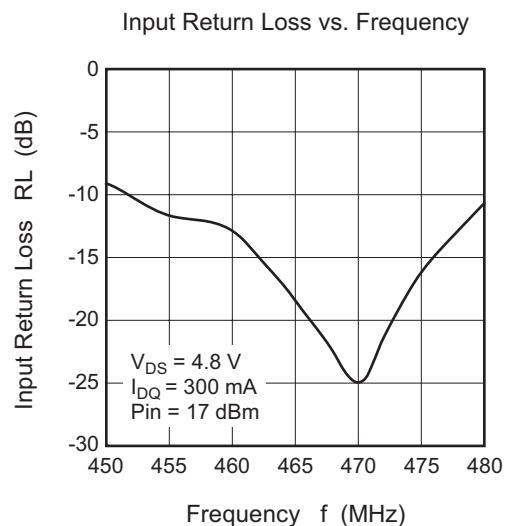
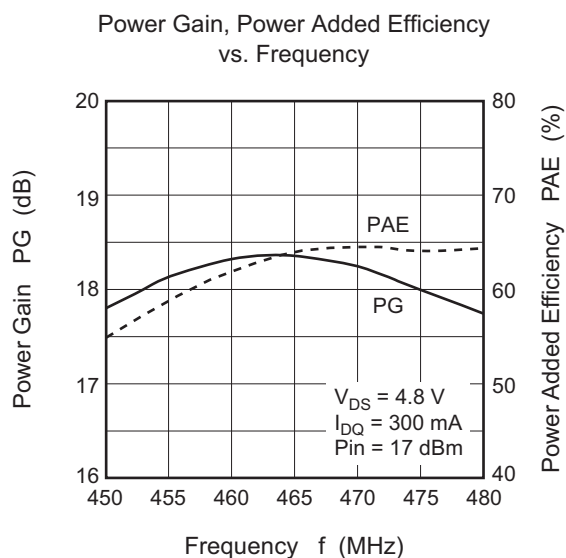
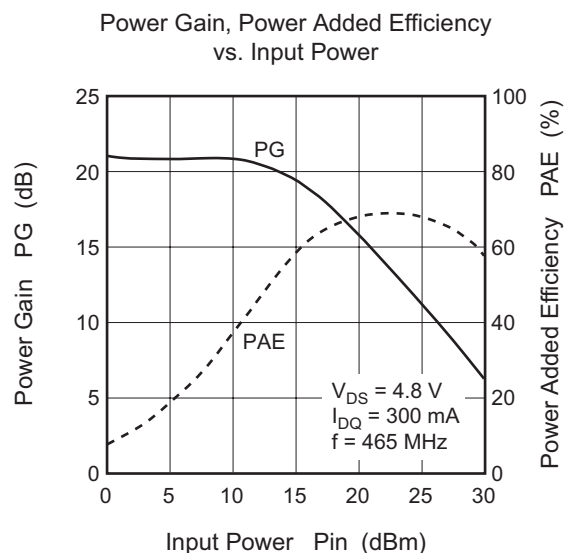
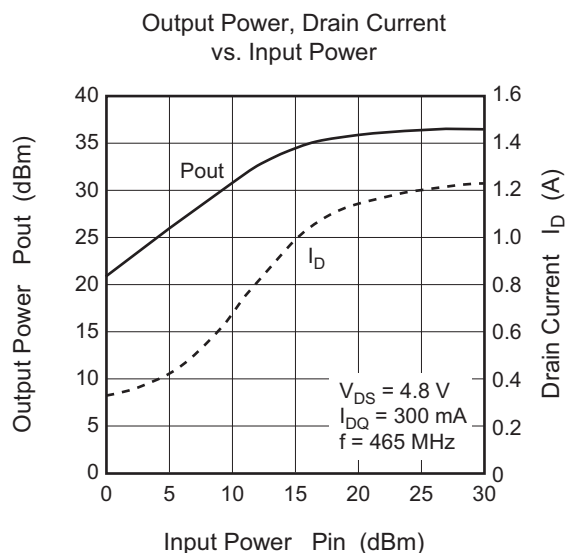
C1, C4, C10, C11	100 pF Chip Capacitor
C2	22 pF Chip Capacitor
C3	5 pF Chip Capacitor
C5, C12	1000 pF Chip Capacitor
C6, C13	1 μF Chip Tantalum Capacitor
C7	18 pF Chip Capacitor
C8	10 pF Chip Capacitor
C9	7 pF Chip Capacitor
L1	8 Turns D: 0.5 mm, ϕ 2.4 mm Enamel Wire
L2	1 nH Chip Inductor
L3	1.8 nH Chip Inductor
R1	670 Ω Chip Resistor
R2	6.8 k Ω Chip Resistor



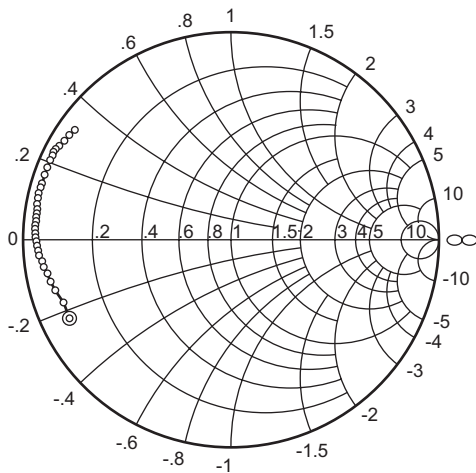
Evaluation Circuit (f = 465 MHz)



C1, C5, C11, C12	100 pF Chip Capacitor
C2, C8	22 pF Chip Capacitor
C3	15 pF Chip Capacitor
C4, C9, C10	10 pF Chip Capacitor
C6, C13	2200 pF Chip Capacitor
C7, C14	1 μ F / 35 V Chip Tantalum Capacitor
L1	1 nH Chip Inductor
L2	1.8 nH Chip Inductor
L3	8 Turns D: 0.5 mm, ϕ 2.4 mm Enamel Wire
R1	670 Ω Chip Resistor
R2	6.8 k Ω Chip Resistor



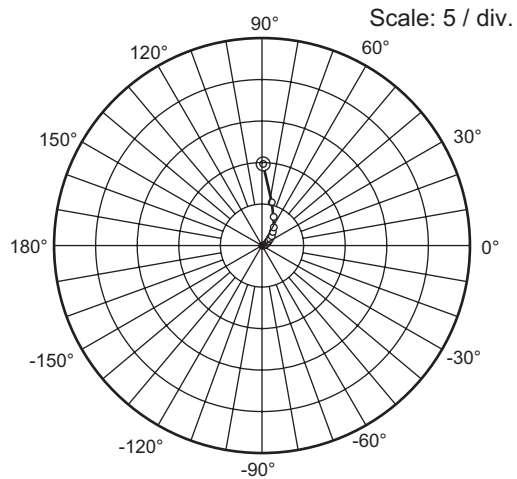
S11 Parameter vs. Frequency



Test condition:

$V_{DS} = 6\text{ V}$, $I_{DQ} = 180\text{ mA}$, $Z_O = 50\ \Omega$
 100 to 1000 MHz (50 MHz step)
 1000 to 2500 MHz (100 MHz step)

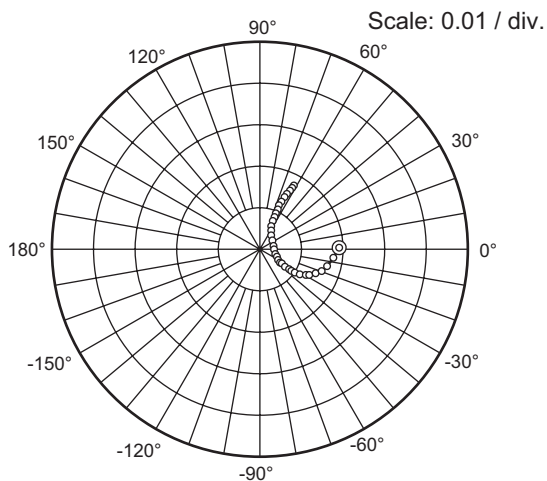
S21 Parameter vs. Frequency



Test condition:

$V_{DS} = 6\text{ V}$, $I_{DQ} = 180\text{ mA}$, $Z_O = 50\ \Omega$
 100 to 1000 MHz (50 MHz step)
 1000 to 2500 MHz (100 MHz step)

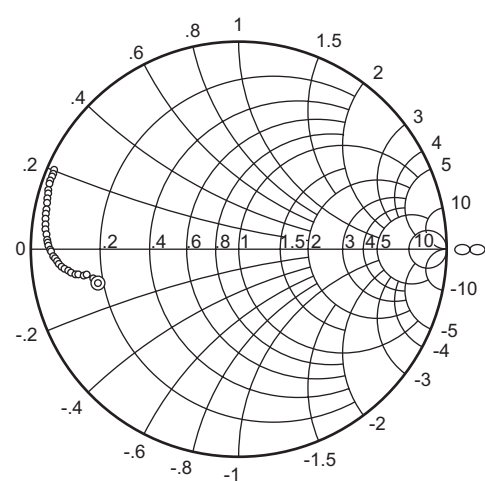
S12 Parameter vs. Frequency



Test condition:

$V_{DS} = 6\text{ V}$, $I_{DQ} = 180\text{ mA}$, $Z_O = 50\ \Omega$
 100 to 1000 MHz (50 MHz step)
 1000 to 2500 MHz (100 MHz step)

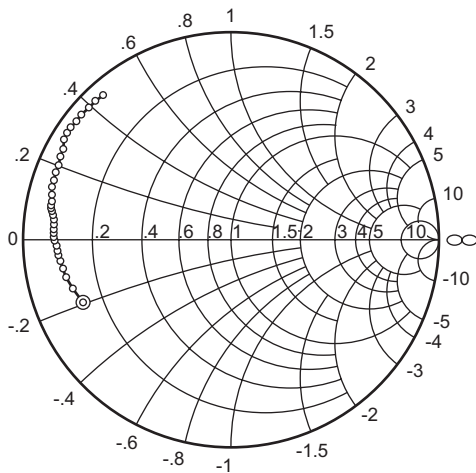
S22 Parameter vs. Frequency



Test condition:

$V_{DS} = 6\text{ V}$, $I_{DQ} = 180\text{ mA}$, $Z_O = 50\ \Omega$
 100 to 1000 MHz (50 MHz step)
 1000 to 2500 MHz (100 MHz step)

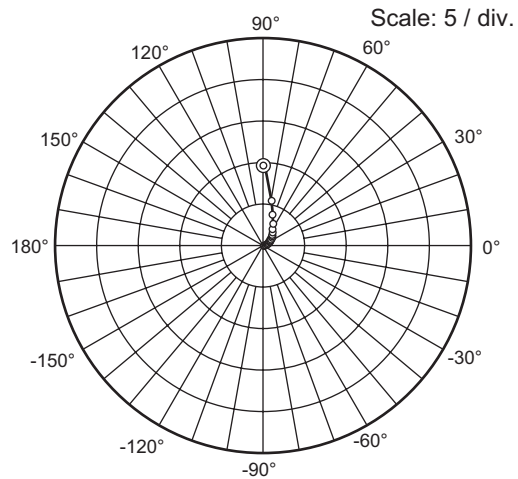
S11 Parameter vs. Frequency



Test condition:

$V_{DS} = 4.8 \text{ V}$, $I_{DQ} = 300 \text{ mA}$, $Z_O = 50 \Omega$
 100 to 1000 MHz (50 MHz step)
 1000 to 2500 MHz (100 MHz step)

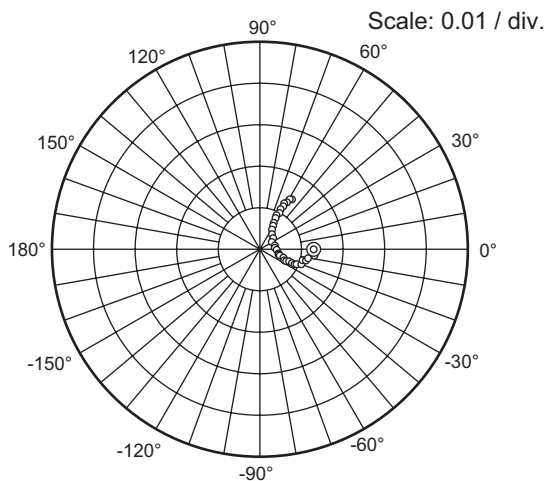
S21 Parameter vs. Frequency



Test condition:

$V_{DS} = 4.8 \text{ V}$, $I_{DQ} = 300 \text{ mA}$, $Z_O = 50 \Omega$
 100 to 1000 MHz (50 MHz step)
 1000 to 2500 MHz (100 MHz step)

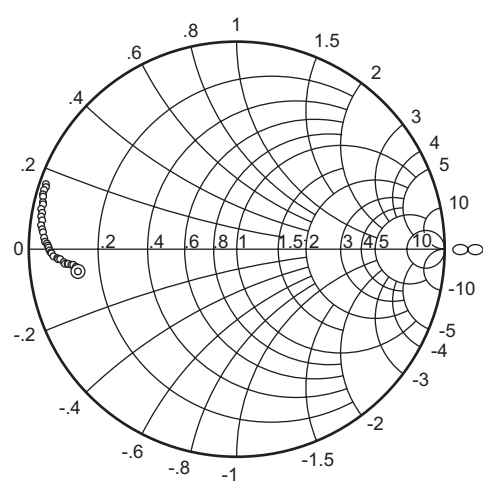
S12 Parameter vs. Frequency



Test condition:

$V_{DS} = 4.8 \text{ V}$, $I_{DQ} = 300 \text{ mA}$, $Z_O = 50 \Omega$
 100 to 1000 MHz (50 MHz step)
 1000 to 2500 MHz (100 MHz step)

S22 Parameter vs. Frequency



Test condition:

$V_{DS} = 4.8 \text{ V}$, $I_{DQ} = 300 \text{ mA}$, $Z_O = 50 \Omega$
 100 to 1000 MHz (50 MHz step)
 1000 to 2500 MHz (100 MHz step)

S Parameter

(V_{DS} = 6 V, I_{DQ} = 180 mA, Z_o = 50 Ω)

f (MHz)	S11		S21		S12		S22	
	MAG	ANG (deg.)	MAG	ANG (deg.)	MAG	ANG (deg.)	MAG	ANG (deg.)
100	0.868	-154.0	9.85	88.8	0.019	1.2	0.706	-166.8
150	0.861	-159.4	5.42	77.2	0.018	-6.3	0.725	-168.9
200	0.882	-163.9	3.64	68.2	0.016	-14.1	0.755	-170.6
250	0.892	-166.8	2.64	58.5	0.016	-19.2	0.768	-170.6
300	0.899	-169.5	2.06	51.8	0.014	-22.1	0.792	-171.2
350	0.910	-171.6	1.61	45.1	0.013	-27.2	0.805	-171.5
400	0.918	-173.4	1.28	40.3	0.013	-29.3	0.827	-172.2
450	0.926	-175.2	1.04	36.0	0.011	-34.1	0.840	-173.1
500	0.932	-176.8	0.84	31.8	0.010	-33.1	0.855	-173.8
550	0.936	-178.2	0.73	28.8	0.009	-34.5	0.869	-174.6
600	0.940	-179.5	0.62	26.4	0.008	-34.6	0.880	-175.6
650	0.941	179.2	0.54	23.1	0.007	-36.5	0.892	-176.5
700	0.944	178.1	0.45	20.2	0.006	-32.7	0.901	-177.3
750	0.945	176.9	0.41	18.3	0.006	-32.0	0.906	-178.0
800	0.944	175.9	0.37	16.4	0.005	-25.3	0.915	-179.4
850	0.944	174.6	0.31	13.9	0.004	-22.3	0.919	180.0
900	0.943	173.4	0.30	12.1	0.004	-15.2	0.929	178.9
950	0.943	172.3	0.26	10.6	0.003	0.3	0.930	178.1
1000	0.946	171.1	0.23	8.6	0.003	9.1	0.936	177.2
1050	0.949	170.2	0.22	7.3	0.003	20.6	0.940	176.5
1100	0.951	169.4	0.21	6.5	0.004	36.9	0.943	175.5
1150	0.952	168.7	0.18	5.3	0.004	40.3	0.944	174.7
1200	0.952	167.8	0.18	4.3	0.004	52.0	0.950	174.1
1250	0.952	167.0	0.16	3.7	0.005	53.2	0.951	173.3
1300	0.952	166.2	0.14	2.2	0.005	56.8	0.949	172.6
1350	0.952	165.4	0.14	1.3	0.006	60.9	0.956	171.7
1400	0.952	164.6	0.13	0.8	0.006	64.0	0.958	171.0
1450	0.952	164.0	0.12	0.1	0.007	62.2	0.957	170.3
1500	0.952	163.3	0.11	-0.8	0.008	65.4	0.956	169.5
1550	0.952	162.1	0.11	-1.8	0.008	65.9	0.959	168.5
1600	0.952	160.8	0.10	-2.7	0.009	65.6	0.960	168.2
1650	0.952	159.7	0.10	-3.6	0.009	65.9	0.960	167.4
1700	0.952	158.5	0.09	-4.5	0.010	66.6	0.962	166.4
1750	0.952	157.3	0.08	-4.7	0.010	66.2	0.967	165.8
1800	0.952	156.4	0.08	-5.0	0.011	66.5	0.968	165.3
1850	0.952	155.7	0.08	-4.7	0.011	66.5	0.965	164.5
1900	0.953	154.7	0.07	-4.9	0.012	67.0	0.967	163.7
1950	0.958	153.9	0.07	-5.2	0.012	67.0	0.976	163.2
2000	0.965	153.6	0.07	-4.6	0.013	65.5	0.972	162.9
2050	0.963	153.3	0.07	-4.9	0.013	65.4	0.972	161.9
2100	0.956	152.9	0.06	-4.2	0.014	65.3	0.976	161.0
2150	0.950	152.2	0.06	-3.5	0.014	65.2	0.981	160.7
2200	0.944	151.6	0.06	-3.8	0.015	63.9	0.977	160.1
2250	0.936	150.7	0.06	-3.5	0.015	63.9	0.977	159.5
2300	0.932	149.3	0.05	-3.4	0.016	63.0	0.978	158.9
2350	0.932	148.1	0.05	-3.6	0.016	62.8	0.981	158.4
2400	0.929	147.3	0.05	-3.0	0.017	63.0	0.977	158.0
2450	0.923	146.3	0.05	-3.6	0.017	61.3	0.977	157.2
2500	0.917	144.9	0.05	-3.0	0.017	61.8	0.980	156.8

S Parameter

(V_{DS} = 4.8 V, I_{DQ} = 300 mA, Z_o = 50 Ω)

f (MHz)	S11		S21		S12		S22	
	MAG	ANG (deg.)	MAG	ANG (deg.)	MAG	ANG (deg.)	MAG	ANG (deg.)
100	0.772	-157.0	9.63	88.9	0.013	-1.0	0.776	-172.1
150	0.794	-162.8	5.54	79.0	0.013	-6.3	0.784	-173.8
200	0.812	-167.3	3.91	71.6	0.012	-11.1	0.799	-174.8
250	0.818	-170.4	2.98	64.7	0.011	-13.5	0.805	-174.8
300	0.824	-173.1	2.36	59.1	0.011	-15.2	0.818	-175.0
350	0.831	-175.0	1.92	53.6	0.011	-20.4	0.824	-175.1
400	0.836	-176.6	1.60	48.7	0.010	-21.4	0.837	-175.4
450	0.841	-178.3	1.36	44.8	0.009	-23.3	0.843	-175.8
500	0.848	-179.9	1.15	40.5	0.008	-22.9	0.859	-176.8
550	0.851	179.0	1.00	37.1	0.008	-22.2	0.868	-177.1
600	0.851	177.7	0.87	33.9	0.007	-24.8	0.874	-177.4
650	0.852	176.3	0.77	30.7	0.006	-24.2	0.887	-177.8
700	0.854	174.7	0.69	27.9	0.006	-20.5	0.896	-178.8
750	0.858	173.3	0.60	24.8	0.005	-18.2	0.901	-179.1
800	0.865	171.9	0.54	22.3	0.005	-15.1	0.905	-179.8
850	0.873	170.8	0.49	20.2	0.005	-12.2	0.911	179.5
900	0.878	169.8	0.45	17.9	0.004	-1.7	0.918	178.9
950	0.880	168.8	0.41	16.1	0.004	4.3	0.922	178.3
1000	0.882	167.7	0.37	14.2	0.004	11.2	0.932	177.8
1050	0.886	166.5	0.35	12.4	0.004	21.6	0.931	177.1
1100	0.889	165.5	0.32	10.7	0.004	29.8	0.935	176.5
1150	0.893	164.4	0.29	8.9	0.004	33.2	0.939	175.8
1200	0.898	163.3	0.27	7.5	0.004	40.9	0.944	175.1
1250	0.902	162.4	0.26	6.2	0.005	46.7	0.943	174.6
1300	0.901	161.3	0.23	4.7	0.005	50.8	0.948	174.1
1350	0.902	160.0	0.22	3.3	0.005	54.5	0.948	173.4
1400	0.904	158.7	0.21	1.8	0.006	57.8	0.954	173.1
1450	0.907	157.7	0.19	0.4	0.006	55.3	0.954	172.5
1500	0.904	156.5	0.18	-0.8	0.007	60.5	0.953	171.6
1550	0.905	155.1	0.17	-2.4	0.007	62.1	0.958	171.0
1600	0.912	153.8	0.16	-3.1	0.007	61.1	0.959	170.7
1650	0.915	152.8	0.15	-4.2	0.008	64.3	0.956	170.4
1700	0.919	151.5	0.14	-5.8	0.008	63.2	0.958	169.3
1750	0.926	149.9	0.14	-6.8	0.009	62.7	0.964	168.9
1800	0.938	148.8	0.13	-7.8	0.009	63.0	0.965	168.4
1850	0.942	147.9	0.13	-8.6	0.010	62.6	0.963	167.8
1900	0.942	146.7	0.12	-9.3	0.010	61.9	0.965	167.0
1950	0.945	145.5	0.11	-10.2	0.010	63.8	0.968	166.6
2000	0.946	144.7	0.11	-10.6	0.011	62.4	0.965	166.3
2050	0.942	143.7	0.11	-11.2	0.011	62.2	0.969	165.5
2100	0.939	142.3	0.10	-11.8	0.012	61.2	0.973	164.9
2150	0.940	140.9	0.10	-12.5	0.012	62.0	0.974	164.6
2200	0.942	139.8	0.09	-13.3	0.012	61.3	0.974	164.2
2250	0.939	138.3	0.09	-14.3	0.013	59.2	0.974	163.4
2300	0.937	136.8	0.08	-15.3	0.013	59.6	0.976	163.0
2350	0.937	135.4	0.08	-16.3	0.014	59.8	0.977	162.9
2400	0.935	134.1	0.08	-17.5	0.014	58.9	0.972	162.0
2450	0.932	132.8	0.07	-18.1	0.014	57.9	0.975	161.5
2500	0.931	131.3	0.07	-18.7	0.014	57.7	0.977	161.2

Package Dimensions

JEITA Package Code	RENESAS Code	Package Name	MASS[Typ.]	Unit: mm
SC-62	PLZZ0004CA-A	UPAK / UPAKV	0.050g	

The mechanical drawing illustrates the dimensions of the RQA0009TXDQS package in millimeters. The top view shows a rectangular body with a central circular feature of diameter $\phi 1$. Key dimensions include a total width of 4.5 ± 0.1 mm, a maximum width of 1.8 mm, and a maximum height of 0.4 mm. The side view shows a maximum height of 1.5 ± 0.1 mm and a maximum width of 0.44 mm. The bottom view shows a maximum width of 0.53 mm, a maximum height of 0.48 mm, and a minimum height of 0.8 mm. The package is shown with a maximum width of 3.0 mm and a maximum height of 4.25 mm. The bottom view also shows a maximum width of 1.5 mm and a maximum height of 0.4 mm. The package is shown with a maximum width of 1.5 mm and a maximum height of 0.4 mm.

Ordering Information

Part Name	Quantity	Shipping Container
RQA0009TXTL-E	1000 pcs.	$\phi 178$ mm reel, 12 mm emboss taping

Notes:

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Renesas Technology America, Inc.
450 Holger Way, San Jose, CA 95134-1368, U.S.A
Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120
Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong
Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd.
10th Floor, No.99, Fushing North Road, Taipei, Taiwan
Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632
Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd.
Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea
Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: <603> 7955-9390, Fax: <603> 7955-9510